

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	80		
D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	41	mJ	
D	Power Dissipation		94	W	
PD	Derate Above 25°C		0.63	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
R _{0JC}	Thermal Resistance, Junction to Case		1.6	°C/W	
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, $L = 15\mu$ H, $I_{AS} = 74$ A, $V_{DD} = 60$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

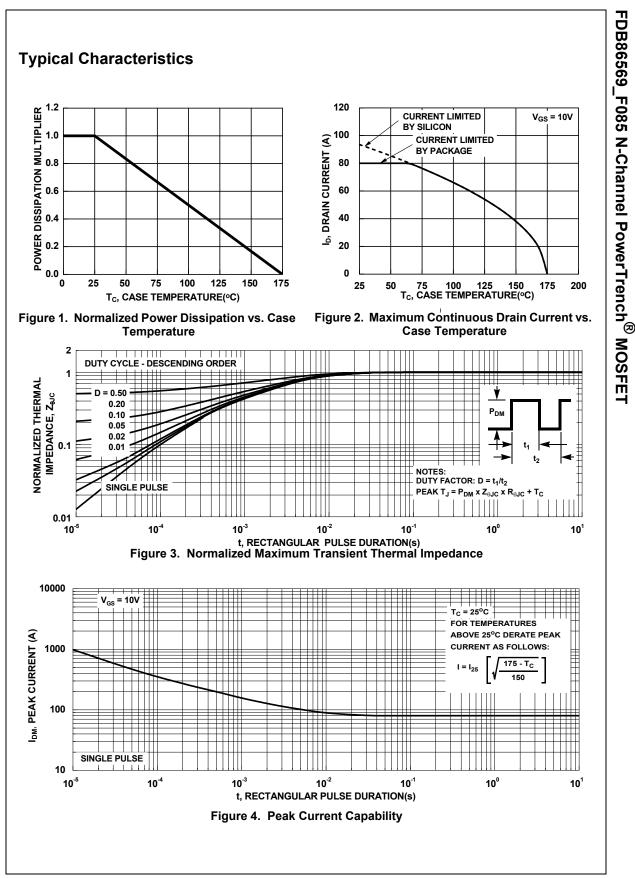
3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

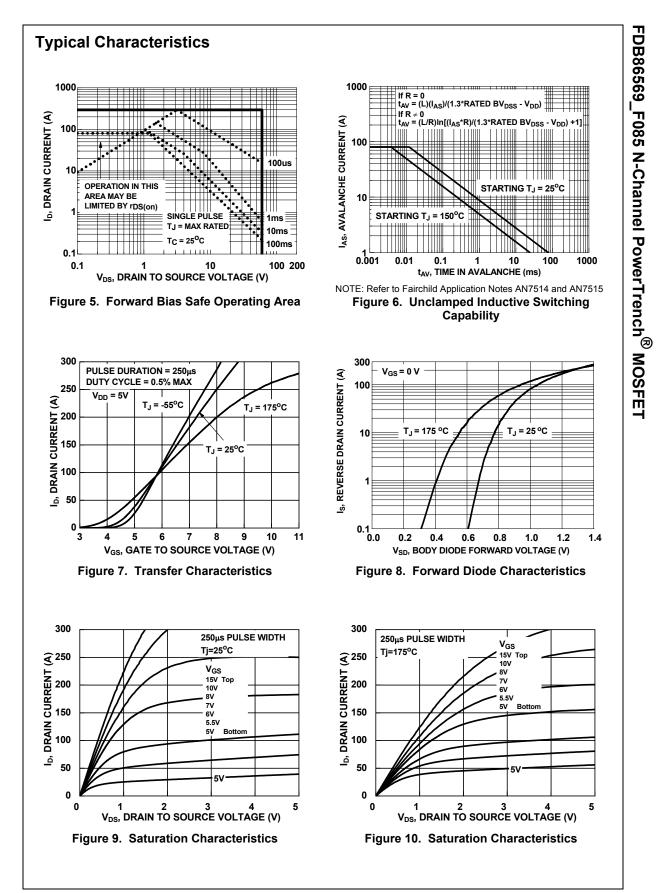
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86569	FDB86569_F085	D2-PAK(TO-263)	330mm	24mm	800 units

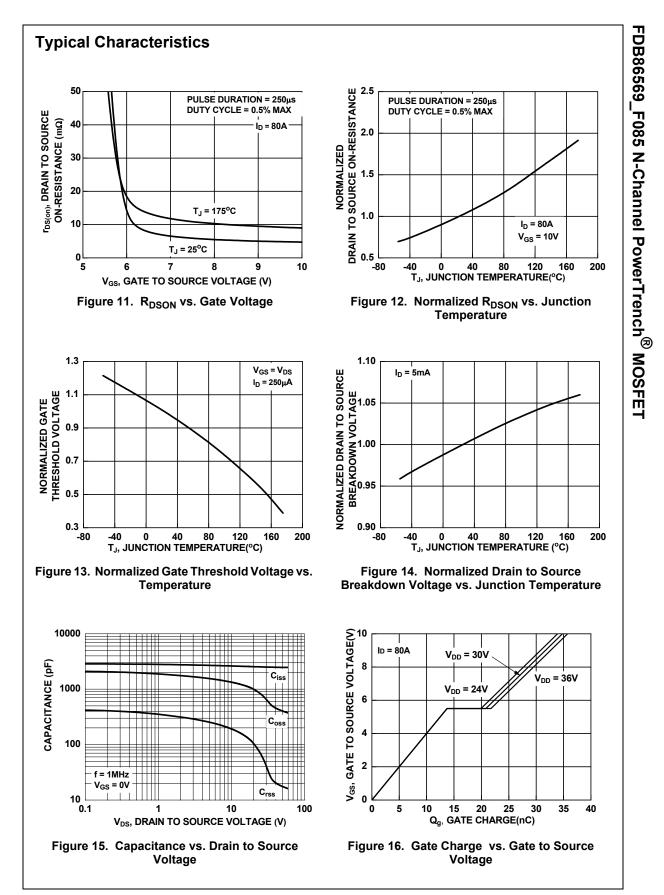
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics					1	
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V	/ _{GS} = 0V	60	_	-	V
VD00		V _{DS} =60V,		-	-	1	μA
DSS	Drain-to-Source Leakage Current		$T_{\rm J} = 175^{\rm o}C$ (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics				-		
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I	_D = 250μA	2.0	2.8	4.0	V
		I _D = 80A,	$T_J = 25^{\circ}C$	-	4.4	5.6	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{\rm J} = 175^{\rm o}C \ ({\rm Note} \ 4)$	-	8.5	10.8	mΩ
C _{iss} C _{oss}	Input Capacitance Output Capacitance	$-V_{DS} = 30 V, V_{GS} = 0V,$		-	2520 690	-	pF pF
					0-00		_
C _{oss}	Output Capacitance	f = 1MHz f = 1MHz		-	690	-	pF
C _{rss}	Reverse Transfer Capacitance			-	47	-	pF
R _g	Gate Resistance			-	2.0	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V_{GS} = 0 to 1	0V V _{DD} = 30V	-	35	52	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2'			4.8	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	14	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	7.4	-	nC
on Witchi	ng Characteristics				-	53	ns
t _{d(on)}	Turn-On Delay			-	15	-	ns
r	Rise Time	V _{DD} = 30V, I	_D = 80A.	-	20	-	ns
d(off)	Turn-Off Delay	$V_{GS} = 10V, R_{GEN} = 6\Omega$		-	22	-	ns
4(0)	Fall Time			-	8	-	ns
t _{off}	Turn-Off Time	-		-	-	45	ns
Drain-S	ource Diode Characteristics				1	1	
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V		-	-	1.25	V
- 30		I _{SD} = 40A, V _{GS} = 0V		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs, V _{DD} =48V		-	52	68	ns
Q _{rr}	Reverse-Recovery Charge			-	43	65	nC

FDB86569_F085 N-Channel PowerTrench[®] MOSFET



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